

### 54F/74F827 ◆ 74F828 10-Bit Buffers/Line Drivers

#### **General Description**

The 'F827 and 'F828 10-bit bus buffers provide high performance bus interface buffering for wide data/address paths or buses carrying parity. The 10-bit buffers have NOR output enables for maximum control flexibility.

The 'F827 and 'F828 are functionally- and pin-compatible to AMD's Am29827 and Am29828. The 'F828 is an inverting version of the 'F827.

#### **Features**

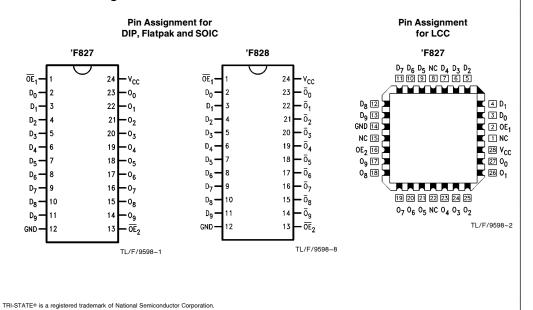
- TRI-STATE® output
- 'F828 is inverting
- Direct replacement for AMD's Am29827 and Am29828

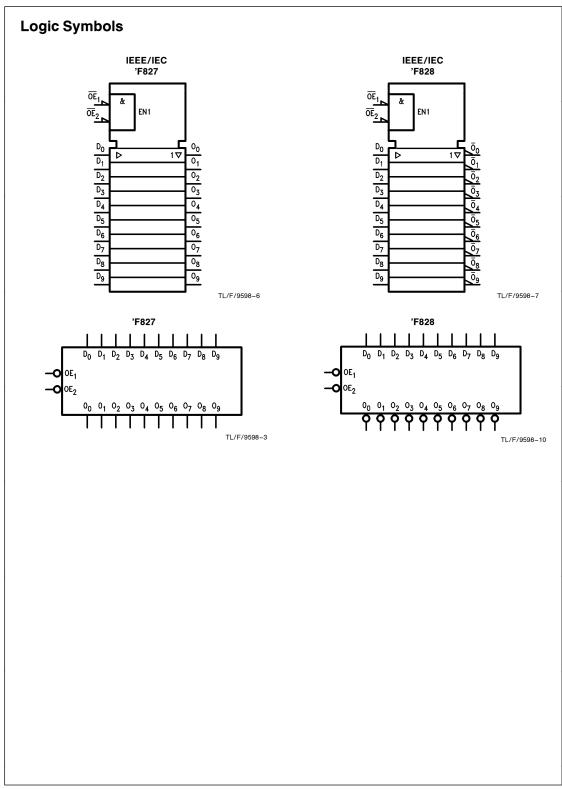
Commercial	Military	Package Number	Package Description
74F827SPC		N24C	24-Lead (0.300" Wide) Molded Dual-In-Line
	54F827SDM (Note 2)	J24F	24-Lead (0.300" Wide) Ceramic Dual-In-Line
74F827SC (Note 1)		M24B	24-Lead (0.300" Wide) Molded Small Outline, JEDEC
	54F827FM (Note 2)	W24C	24-Lead Cerpack
	54F827LM (Note 2)	E28A	24-Lead Ceramic Leadless Chip Carrier, Type C
74F828SPC		N24C	24-Lead (0.300" Wide) Molded Dual-In-Line
74F828SC (Note 1)		M24B	24-Lead (0.300" Wide) Molded Small Outline, JEDEC

Note 1: Devices also available in 13" reel. Use suffix = SCX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = SDMQB, FMQB and LMQB.

#### **Connection Diagrams**





### **Unit Loading/Fan Out**

		54F/74F					
Pin Names	Description	U.L. HIGH/LOW	Input I <sub>IH</sub> /I <sub>IL</sub> Output I <sub>OH</sub> /I <sub>OL</sub>				
$\overline{OE}_1, \overline{OE}_2$	Output Enable Input	1.0/1.0	20 μA/ - 0.6 mA				
$D_0-D_7$	Data Inputs	1.0/1.0	20 μA/ - 0.6 mA				
O <sub>0</sub> -O <sub>7</sub>	Data Outputs, TRI-STATE	600/106.6 (80)	-12 mA/64 mA (48 mA)				

#### **Functional Description**

The 'F827 and 'F828 are line drivers designed to be employed as memory address drivers, clock drivers and bus-oriented transmitters/receivers which provide improved PC board density. The devices have TRI-STATE outputs controlled by the Output Enable (OE) pins. The outputs can sink 64 mA (48 mA mil) and source 15 mA. Input clamp diodes limit high-speed termination effects.

#### **Function Table**

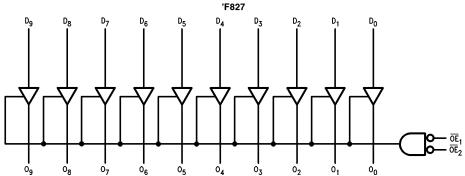
Inp	uts	Out	puts	
ŌĒ	Dn	Ó	) <sub>n</sub>	Function
	υn	'F827 'F828		
L	Н	Н	L	Transparent
L	L	L	Н	Transparent
Н	X	Z	Z	High Z

H = HIGH Voltage level

L = LOW Voltage Level Z = High Impedance

X = Immaterial

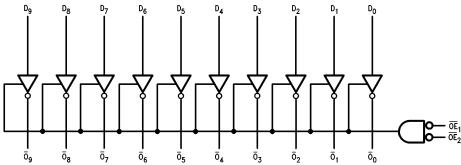
#### **Logic Diagrams**



TL/F/9598-4

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

#### 'F828



TL/F/9598-11

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

#### **Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

V<sub>CC</sub> Pin Potential to

Ground Pin -0.5V to +7.0V
Input Voltage (Note 2) -0.5V to +7.0V
Input Current (Note 2) -30 mA to +5.0 mA

Voltage Applied to Output

in HIGH State (with  $V_{CC} = 0V$ )

 $\begin{array}{ll} \mbox{Standard Output} & -0.5\mbox{V to V}_{\mbox{CC}} \\ \mbox{TRI-STATE Output} & -0.5\mbox{V to } +5.5\mbox{V} \end{array}$ 

Current Applied to Output

in LOW State (Max) twice the rated I<sub>OL</sub> (mA)

**Note 1:** Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

# Recommended Operating Conditions

Free Air Ambient Temperature

Supply Voltage

Military +4.5V to +5.5V Commercial +4.5V to +5.5V

#### **DC Electrical Characteristics**

Symbol	Parameter			54F/74F	:	Units	V <sub>CC</sub>	Conditions	
Symbol	raiaile			Тур	Max	Oilles	•66	Conditions	
$V_{IH}$	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal	
V <sub>IL</sub>	Input LOW Voltage	Input LOW Voltage			0.8	V		Recognized as a LOW Signal	
V <sub>CD</sub>	Input Clamp Diode Voltage				-1.2	V	Min	$I_{\text{IN}} = -18 \text{ mA}$	
V <sub>OH</sub>	Output HIGH Voltage	54F 10% V <sub>CC</sub> 54F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub> 74F 5% V <sub>CC</sub>	2.4 2.0 2.4 2.0 2.7			V	Min	$\begin{split} I_{OH} &= -3 \text{ mA} \\ I_{OH} &= -12 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \\ I_{OH} &= -15 \text{ mA} \\ I_{OH} &= -3 \text{ mA} \end{split}$	
V <sub>OL</sub>	Output LOW Voltage	54F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub>			0.55 0.55	٧	Min	I <sub>OL</sub> = 48 mA I <sub>OL</sub> = 64 mA	
I <sub>IH</sub>	Input HIGH Current	54F 74F			20.0 5.0	μΑ	Max	$V_{IN} = 2.7V$	
I <sub>BVI</sub>	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μΑ	Max	V <sub>IN</sub> = 7.0V	
I <sub>CEX</sub>	Output HIGH Leakage Current	54F 74F			250 50	μΑ	Max	$V_{OUT} = V_{CC}$	
V <sub>ID</sub>	Input Leakage Test	74F	4.75			٧	0.0	$I_{\text{ID}} = 1.9  \mu\text{A}$ All Other Pins Grounded	
I <sub>OD</sub>	Output Leakage Circuit Current	74F			3.75	μΑ	0.0	V <sub>IOD</sub> = 150 mV All Other Pins Grounded	
I <sub>IL</sub>	Input LOW Current				-0.6	mA	Max	V <sub>IN</sub> = 0.5V	
l <sub>OZH</sub>	Output Leakage Current				50	μΑ	Max	V <sub>OUT</sub> = 2.7V	
l <sub>OZL</sub>	Output Leakage Curr	ent			-50	μΑ	Max	V <sub>OUT</sub> = 0.5V	
los	Output Short-Circuit (	Current	-100		-225	mA	Max	V <sub>OUT</sub> = 0V	

#### **DC Electrical Characteristics** (Continued)

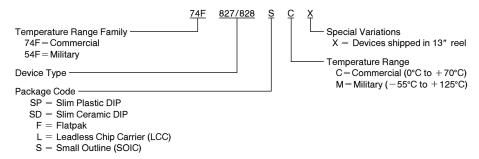
Symbol	Parameter		54F/74F		Units	V <sub>CC</sub>	Conditions	
	T didilecter	Min	Тур	Max	Omis		Conditions	
I <sub>ZZ</sub>	Bus Drainage Test			500	μΑ	0.0V	V <sub>OUT</sub> = 5.25V	
I <sub>CCH</sub>	Power Supply Current ('F827)		30	45	mA	Max	V <sub>O</sub> = HIGH	
I <sub>CCL</sub>	Power Supply Current ('F827)		60	90	mA	Max	$V_O = LOW$	
I <sub>CCZ</sub>	Power Supply Current ('F827)		40	60	mA	Max	V <sub>O</sub> = HIGH Z	
Icch	Power Supply Current ('F828)		14	20	mA	Max	V <sub>O</sub> = HIGH	
ICCL	Power Supply Current ('F828)		56	85	mA	Max	$V_O = LOW$	
Iccz	Power Supply Current ('F828)		35	50	mA	Max	V <sub>O</sub> = HIGH Z	

#### **AC Electrical Characteristics**

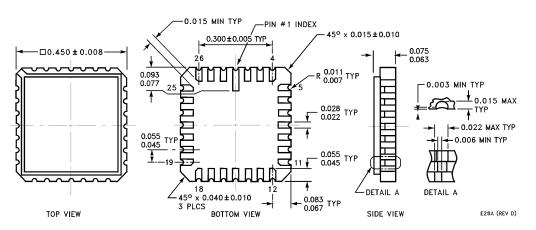
Symbol	Parameter				T <sub>A</sub> , V <sub>C</sub>	4F <sub>C</sub> = Mil 50 pF	74F  T <sub>A</sub> , V <sub>CC</sub> = Com C <sub>L</sub> = 50 pF		Units
		Min	Тур	Max	Min	Max	Min	Max	
t <sub>PLH</sub>	Propagation Delay Data to Output ('F827)	1.0 1.5	3.0 3.3	5.5 5.5	1.0 1.5	7.5 7.0	1.0 1.5	6.5 6.0	ns
t <sub>PLH</sub>	Propagation Delay Data to Output ('F828)	1.0 1.0	3.0 2.0	5.0 4.0			1.0 1.0	5.5 4.0	ns
t <sub>PZH</sub>	Output Enable Time  OE to On	3.0 3.5	5.7 6.8	9.0 11.5	2.5 3.0	10.0 12.5	2.5 3.0	9.5 12.0	ns
t <sub>PHZ</sub>	Output Disable Time  OE to On	1.5 1.0	3.3 3.5	8.0 8.0	1.5 1.0	9.0 9.0	1.5 1.0	8.5 8.5	ns

#### **Ordering Information**

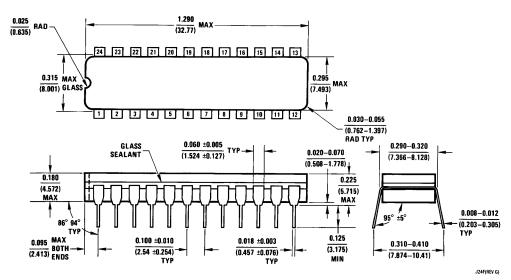
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



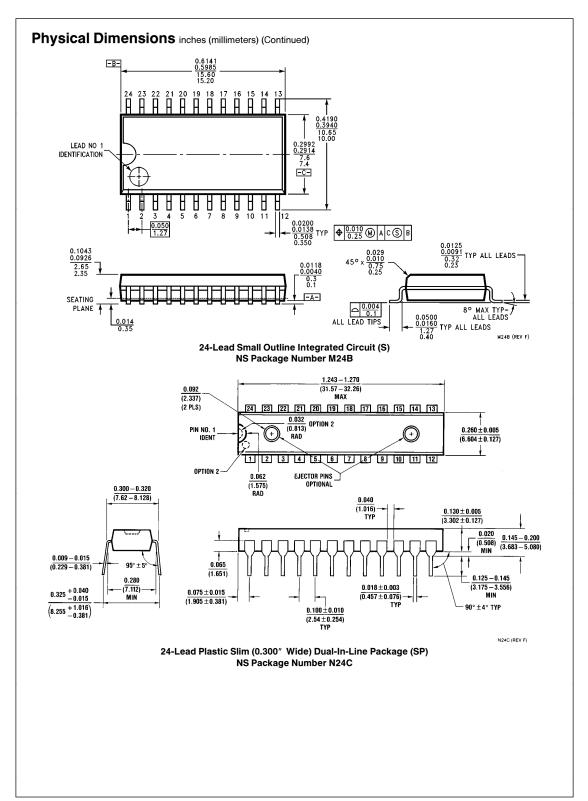




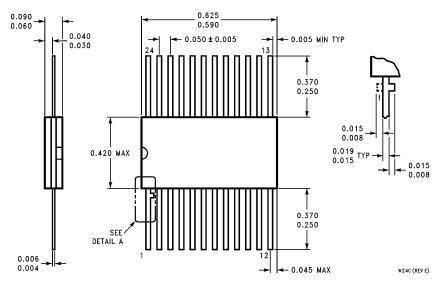
28-Lead Ceramic Leadless Chip Carrier (L) NS Package Number E28A



24-Lead (0.300" Wide) Ceramic Dual-In-Line Package (SD) NS Package Number J24F



### Physical Dimensions inches (millimeters) (Continued)



24-Lead Ceramic Flatpak (F) NS Package Number W24C

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# 54F827 10-Bit Buffer/Line Driver

## **Contents**

- General Description
- Features
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# **General Description**

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# **Features**

- TRI-STATE® output
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- Direct replacement for AMD's Am29827 and Am29828

# **Datasheet**

Title	Size (in Kbytes)	Date	View Online	<b>X Download</b>	Receive via Email
54F827 10-Bit Buffers/Line Drivers	164 Kbytes	9-Dec-97	View Online	Download	Receive via Email

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# Package Availability, Models, Samples & Pricing

Part Number	Package		Status	Models		Samples &	<b>Budgetary Pricing</b>		Std Pack	Package
rart Number	Type	# pins		SPICE	IBIS	Electronic Orders	Quantity	\$US each	I I	Marking
5962-9209001M3A	LCC	28	Full production	N/A	N/A	X	50+	\$26.0000	tray of 25	[logo]¢Z¢S¢4¢A 54F827LMQB Q¢M \$E5962- 9209001M3A
54F827SDMQB	Cerdip	24	Full production	N/A	N/A		50+	\$11.3000	tube of 15	[logo]¢Z¢S¢4¢A\$E 54F827SDMQB /Q¢M 5962-9209001MLA

[Information as of 1-Sep-2000]

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